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DESCRIPTION

The PA assembly for Custom MVP uses two RF power transistors to provide a power output of 25 watts. The output power is adjustable from 8 to 25 watts by power adjust potentiometer R8. A single transistor is used in the power adjust circuit.

Supply voltage (A+) for the PA is connected from jack J1 on the back of the unit through FL210-C5 on the side of the radio. C201, C202 and L12 prevent RF from getting on the power leads. Diode CR201 will cause the main fuse in the fuse assembly to blow if the polarity of the power leads is reversed, providing reverse voltage protection for the radio.

Centralized metering jack J5 is provided for use with GE Test Set Model 4EX3All or Test Kit 4EX8K12. The Test Set meters power control voltage, Ampl-1 drive (exciter output), and PA voltage and current.

stabilizing and feed network consisting of C6, L3, L4 and R4. The collector voltage of Q201 is metered through R7 at J5.

The output of Q201 is coupled to the base of Class C driver Q202 through a matching network consisting of L5, L6, C12, C13, C14 and R5. Collector voltage to Q202 is applied through collector stabilizing and feed network C15, L8, L11 and R6.

Collector current for Q202 is metered across tapped manganin resistor R9 at J5 (PA Current). The reading is taken on the one-Volt scale with the High Sensitivity button pressed, and read as 10 amperes full scale.

Following Q202 is a matching network (L9, L10, C19, C20 and C21) that matches the output of Q202 to the 50-ohm microstrip impedance (W1) in the low pass filter. C22 acts as a DC blocking capacitor.

The PA output is coupled through the low-pass filter to the antenna through antenna relay K1.

CIRCUIT ANALYSIS

RF AMPLIFIERS

The exciter output is coupled through an RF cable to PA input jack J1. The RF is coupled through a matching network to the base of Class C amplifier Q201. The network matches the 50-ohm input to the base of Q201, and consists of T1, C4 and L2. L1, R3 and C3 comprise a stabilizing network in the base circuit of Q201.

Part of the RF input is rectified by CR1 and applied to voltage divider R1 and R2. This voltage is used to meter the AMPL-1 drive at J5.

Collector voltage to Q201 (Ampl-1) is controlled by power control transistor, Q215 and is applied through a collector

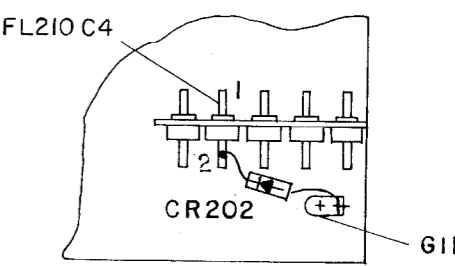
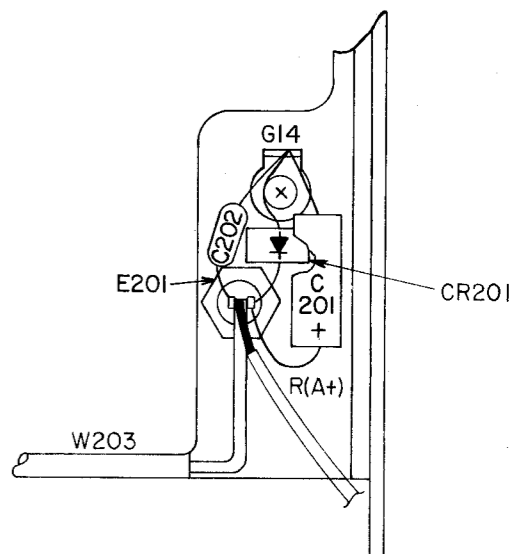
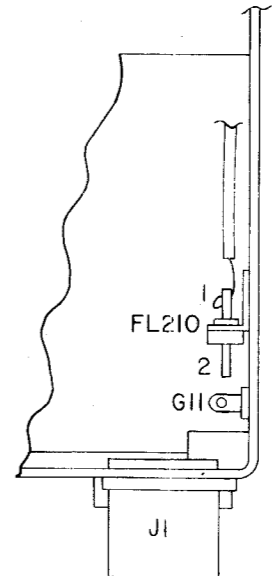
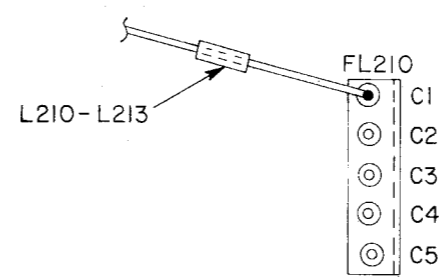
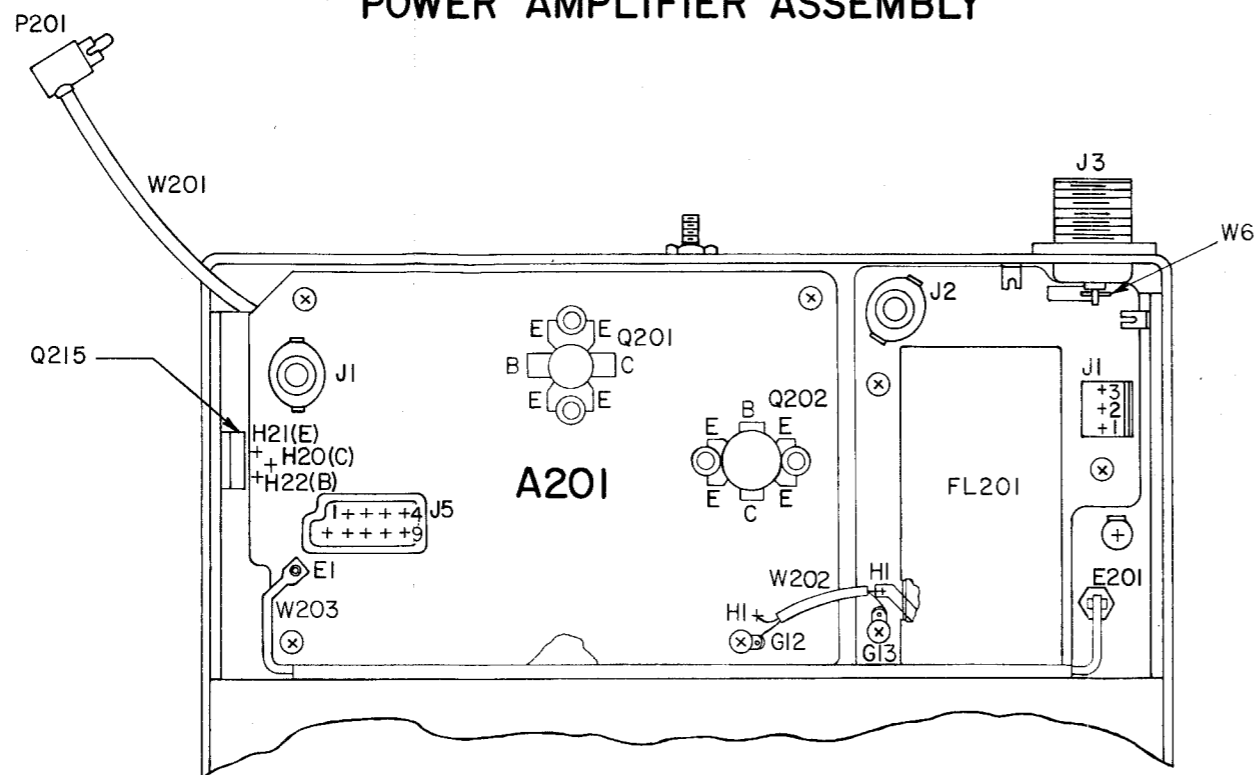
WARNING

The RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

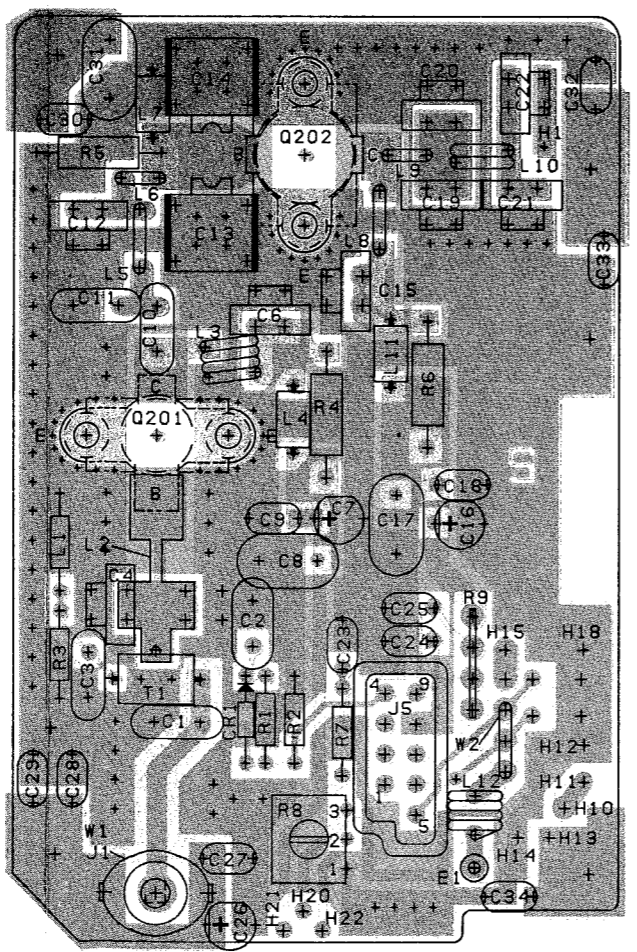
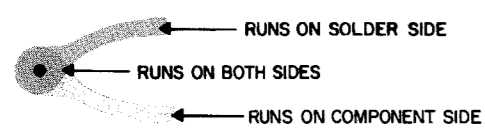
POWER ADJUST CIRCUIT

The power adjust circuit consists of R8 and Q215. R8 controls the base voltage and conduction of Q215. Q215 is connected in series with the collector feed network for Q201, thereby controlling the drive to Q202 and the output power. R8 is adjusted to provide the desired output power.

POWER AMPLIFIER ASSEMBLY



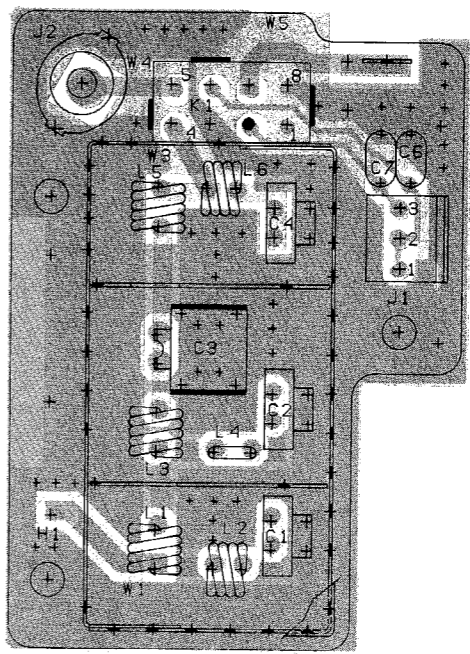
(19C327306, Rev. 1)



CONNECTION CHART

FROM	TO	WIRE SIZE
H13	H14	DB

FILTER BOARD

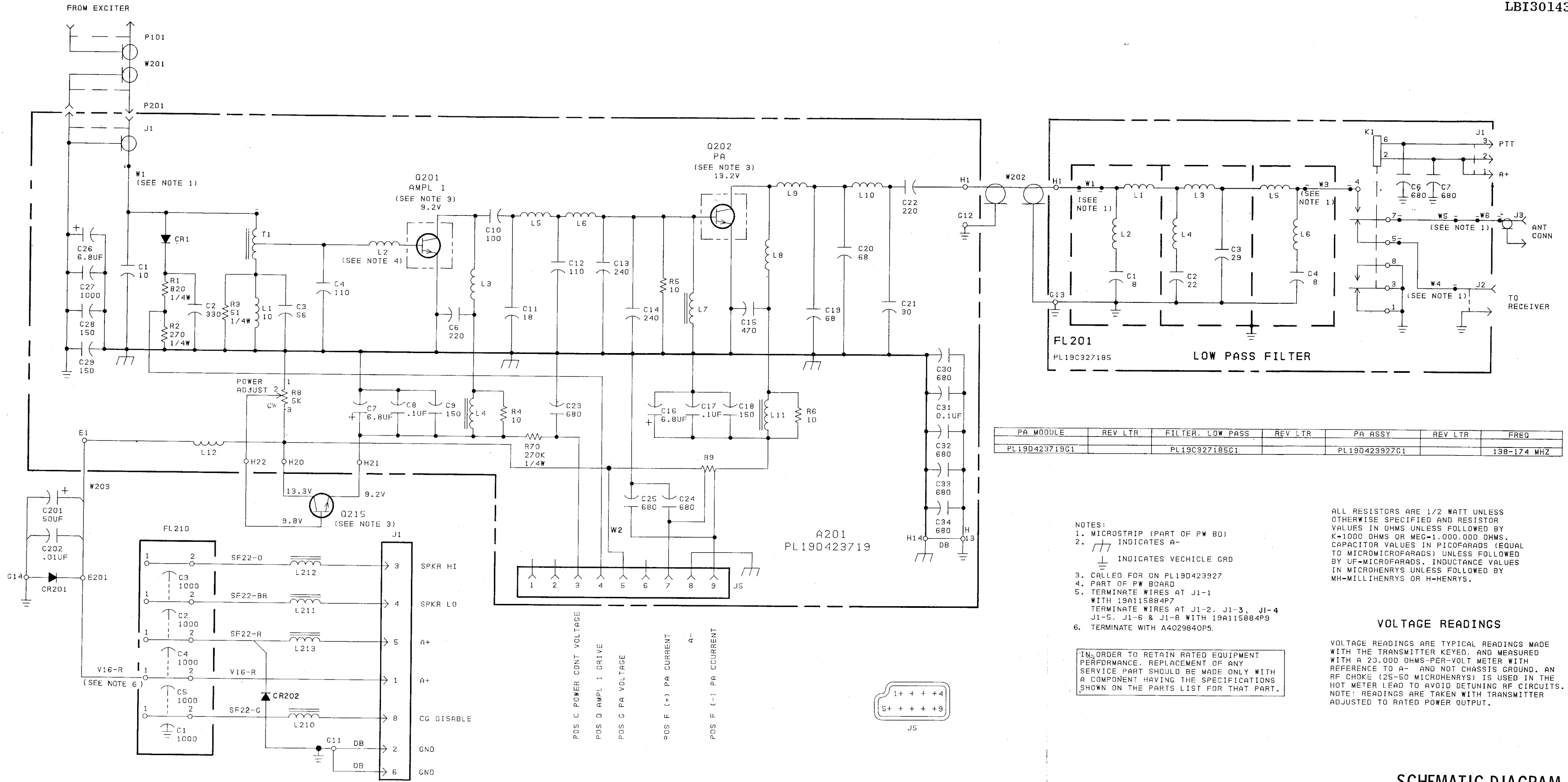


(19C327186, Rev. 1)
 (19B227410, Sh. 2, Rev. 1)
 (19B227410, Sh. 3, Rev. 1)

OUTLINE DIAGRAM

138—174 MHz POWER AMPLIFIER

(19C327248, Rev. 2)
 (19B227232, Sh. 2, Rev. 2)
 (19B227232, Sh. 3, Rev. 2)



(19R622219, Rev. 7)

SCHEMATIC DIAGRAM

138-174 MHz POWER AMPLIFIER

PARTS LIST

LBI30144B

138-174 MHz, 25 WATT POWER AMPLIFIER
19D423927G1

SYMBOL	GE PART NO.	DESCRIPTION
A201		POWER AMPLIFIER MODULE 19D423719G1
----- CAPACITORS -----		
C1	7489162P6	Silver mica: 10 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C2	7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C3	7489162P21	Silver mica: 56 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C4	19A116679P110J	Mica: 110 pf ±5%, 250 VDCW.
C6	19A116679P220J	Mica: 220 pf ±5%, 250 VDCW.
C7	19A134202P15	Tantalum: 6.8 μf ±20%, 35 VDCW.
C8	19A116080P107	Polyester: 0.1 μf ±10%, 50 VDCW.
C9	19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C10	7489162P27	Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C11	19A134666P1	Silver mica: 18 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C12	19A116679P110J	Mica: 110 pf ±5%, 250 VDCW.
C13 and C14	19A116952P240J	Silver mica: 240 pf ±5%, 250 VDCW; sim to Underwood Type J1HF.
C15	19A116679P470K	Mica: 470 pf ±10%, 250 VDCW.
C16	19A134202P15	Tantalum: 6.8 μf ±20%, 35 VDCW.
C17	19A116080P107	Polyester: 0.1 μf ±10%, 50 VDCW.
C18	19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C19 and C20	19A116679P68J	Mica: 68 pf ±5%, 250 VDCW.
C21	19A116679P30J	Metallized teflon: 30 pf ±5%, 250 VDCW.
C22	19A116679P220J	Mica: 220 pf ±5%, 250 VDCW.
C23 thru C25	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C26	19A134202P15	Tantalum: 6.8 μf ±20%, 35 VDCW.
C27	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C28 and C29	19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C30	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C31	19A116080P107	Polyester: 0.1 μf ±10%, 50 VDCW.
C32 thru C34	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
----- DIODES AND RECTIFIERS -----		
CR1	19A115250P1	Silicon, fast recovery, 225 mA, 50 PIV.
----- TERMINALS -----		
E1	19A134263P1	Contact, electrical: sim to Selectro X-L-070174-1.
----- JACKS AND RECEPTACLES -----		
J1	19A130924G1	Connector, coaxial: jack type; sim to Cinch 14H11613.
J5	19B219374G1	Connector: 9 contacts.

SYMBOL	GE PART NO.	DESCRIPTION
----- INDUCTORS -----		
L1	19B209420P125	Coil, RF: 10.0 μh ±10%, 3.10 ohms DC res max; sim to Jeffers 4446-4. (Part of printed board 19D423718P1).
L2		
L3	19A136530P1	Coil.
L4	19A129773G1	Coil.
L5	19A136532P1	Coil.
L6	19A129575P1	Coil.
L7	19A129773G1	Coil.
L8	19A136531P1	Coil.
L9	19A129575P1	Coil.
L10	19A136533P1	Coil.
L11	19A129773G1	Coil.
L12	19A129569P1	Coil.
----- RESISTORS -----		
R1	3R152P821J	Composition: 820 ohms ±5%, 1/4 w.
R2	3R152P271J	Composition: 270 ohms ±5%, 1/4 w.
R3	3R152P510J	Composition: 51 ohms ±5%, 1/4 w.
R4 thru R6	3R77P100J	Composition: 10 ohms ±5%, 1/2 w.
R7	3R152P274J	Composition: 270,000 ohms ±5%, 1/4 w.
R8	19A116559P102	Variable, cermet: 5000 ohms ±20%, .5 w; sim to CTS Series 360.
R9	19C320212P2	Shunt resistor.
----- TRANSFORMERS -----		
T1	19A129564G1	Transformer.
----- CABLES -----		
W1		(Part of printed board 19D423718P1).
W2	19A136532P1	Coil.
----- CAPACITORS -----		
C201	19A115680P4	Electrolytic: 50 μf +150% -10%, 25 VDCW; sim to Mallory Type TTX.
C202	19A116080P101	Polyester: 0.01 μf ±10%, 50 VDCW.
----- DIODES AND RECTIFIERS -----		
CR201	19A116783P1	Silicon.
CR202	4037822P1	Silicon.
----- TERMINALS -----		
E201	7143206P1	Terminal, standoff.
----- FILTERS -----		
FL201		COMPONENT BOARD 19C327185G1
----- CAPACITORS -----		
C1	19A116679P8D	Metallized teflon: 8 pf ±.5 pf, 250 VDCW.
C2	19A116679P22J	Metallized teflon: 22 pf ±5%, 250 VDCW.
C3	19A116795P29J	Metallized teflon: 29 pf ±5%, 250 VDCW; sim to Underwood Type J1HF.
C4	19A116679P8D	Metallized teflon: 8 pf ±.5 pf, 250 VDCW.
C6 and C7	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
----- INDUCTORS -----		
L1	19A129569P1	Coil.

SYMBOL	GE PART NO.	DESCRIPTION
L2	19A129570P1	Coil.
L3	19A129569P1	Coil.
L4	19A129575P1	Coil.
L5	19A129569P1	Coil.
L6	19A129570P1	Coil.
----- JACKS AND RECEPTACLE -----		
J1	19A116659P55	Connector, printed wiring: 3 contacts; sim to Molex 09-65-1031.
J2	19A130924G1	Connector, coaxial: jack type; sim to Cinch 14H11613.
----- RELAYS -----		
K1	19B209558P1	Hermetic sealed: 180-330 ohms coil res, 2 form C contacts, 8.0 to 16.3 VDC; sim to GE 3SAV1760A2.
----- CABLES -----		
W1		(Part of printed board 19C327184P1).
W3 thru W5		(Part of printed board 19C327184P1).
W6	19A136512P1	Antenna strap.
----- FILTERS -----		
FL210		FILTER ASSEMBLY 19A133680G1
----- CAPACITORS -----		
C1 thru C5	5493392P7	Ceramic, feed-thru: 1000 pf +100% -0%, 500 VDCW; sim to Allen-Bradley Type FA5C.
----- TERMINALS -----		
G11 thru G14	7135118P2	Terminal, solderless.
----- JACKS AND RECEPTACLES -----		
J1		Connector. Includes: Shell. Contacts, male: wire size 14-20; sim to AMP 60528-1. Contacts, male: wire size 22-30; sim to AMP 60910-1.
J3	4029493P1	Connector, receptacle: coaxial; sim to Amphenol 83-798.
----- INDUCTORS -----		
L210 thru L213	19A126140P3	Core, toroidal, ferrite: sim to Stackpole 88-31959.
----- PLUGS -----		
P201		(Part of W201).
----- TRANSISTORS -----		
Q201	19A134340P1	Silicon, NPN.
Q202	19A134340P2	Silicon, NPN.
Q215	19A116742P1	Silicon, NPN.
----- CABLES -----		
W201	5491689P91	Cable, RF: approx 7-1/2 inches long.
W202	19A136529G2	Cable: approx 2 inches long.
W203	19B227302P1	Jumper.
----- MISCELLANEOUS -----		
	19C321982P1	Insulator. (Located under A201).
	N84P13003C6	Machine screw, flathead, Phillips: No. 6-32 x 3/16. (Secures FL210).

SYMBOL	GE PART NO.	DESCRIPTION
	4033714P11	Terminal, solderless: sim to Zierick 349. (Solders to FL201).
	N44P9006C6	Screw, machine: No. 4-40 x 3/8. (Secures Q201 and Q202).
	19A116023P1	Insulator, plate. Dupont No. 300 Kapton H. (Located under Q215).
	19A134016P1	Insulator, bushing. (Used with Q215).
	19B201074P204	Tap screw, Phillips POZIDRIV®: No. 4-40 x 1/4. (Secures J3).
	7878243P11	Hex nut: No. 8-32. (Secures stud that mates with wing nut securing radio to case).